

# CAN FD Transceiver, High Speed NCV7357

#### Description

The NCV7357 CAN FD transceiver is the interface between a controller area network (CAN) protocol controller and the physical bus. The transceiver provides differential transmit capability to the bus and differential receive capability to the CAN controller.

The NCV7357 is an addition to the CAN high-speed transceiver family complementing NCV7344 CAN stand-alone transceivers and previous generations such as AMIS42665, AMIS3066x, etc.

The NCV7357 guarantees additional timing parameters to ensure robust communication at data rates beyond 1 Mbps to cope with CAN flexible data rate requirements (CAN FD). These features make the NCV7357 an excellent choice for all types of HS–CAN networks, in nodes that require only a basic CAN capability.

#### **Features**

- Compliant with ISO 11898-2:2016
- CAN FD Timing Specified up to 5 Mbps
- V<sub>IO</sub> Pin on NCV7357–3 Version Allowing Direct Interfacing with 3 V to 5 V Microcontrollers
- Low Current, Listen Only Silent Mode
- Low Electromagnetic Emission (EME) and High Electromagnetic Immunity
- Very Low EME without Common-mode (CM) Choke
- No Disturbance of the Bus Lines with an Unpowered Node
- Transmit Data (TxD) Dominant Timeout Function
- Under All Supply Conditions the Chip Behaves Predictably
- Very High ESD Robustness of Bus Pins, >8 kV System ESD Pulses

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- Thermal Protection
- Bus Pins Short Circuit Proof to Supply Voltage and Ground
- Bus Pins Protected Against Transients in an Automotive Environment
- These are Pb-free Devices

#### Quality

- Wettable Flank Package for Enhanced Optical Inspection
- AEC-Q100 Grade 0 Qualified and PPAP Capable

#### **Typical Applications**

- Automotive
- Industrial Networks



SOIC-8 D SUFFIX CASE 751-07



DFNW8 MW SUFFIX CASE 507AB

#### MARKING DIAGRAM



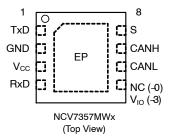


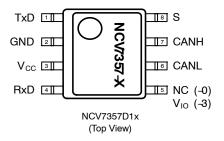
NV7357-X = Specific Device Code

A = Assembly Location

L = Wafer Lot Y = Year W = Work Week ■ Pb-Free Package

#### **PIN ASSIGNMENT**





#### ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 11 of this data sheet.

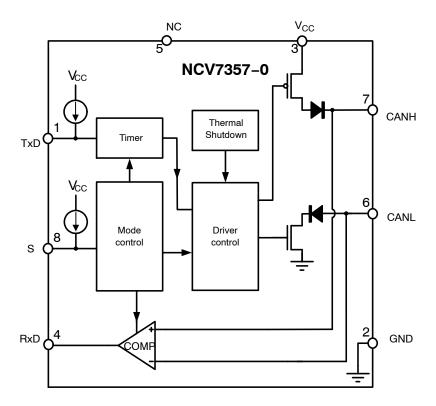


Figure 1. NCV7357-0 Block Diagram

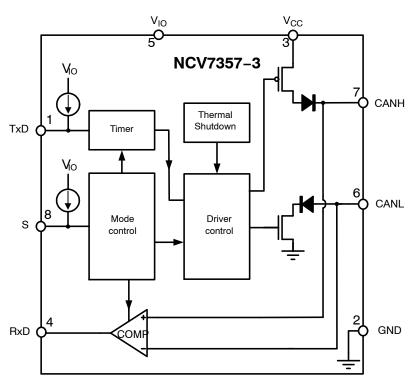


Figure 2. NCV7357-3 Block Diagram

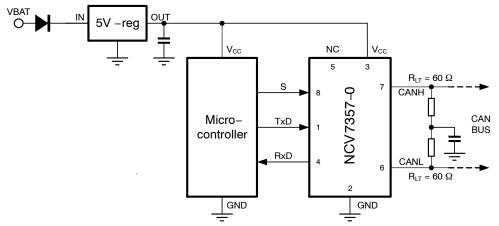


Figure 3. Application Diagram NCV7357-0

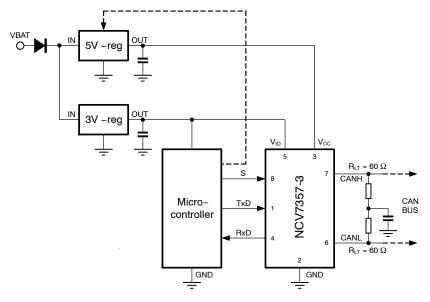


Figure 4. Application Diagram NCV7357-3

**Table 1. PIN FUNCTION DESCRIPTION** 

| Pin | Name            | Description  |
|-----|-----------------|--|
| 1   | TxD             | Transmit data input; low input → dominant driver; internal pull-up current                       |
| 2   | GND             | Ground   |
| 3   | V <sub>CC</sub> | Supply voltage   |
| 4   | RxD             | Receive data output; dominant transmitter → low output   |
| 5   | NC              | Not connected. On NCV7357–0 only   |
| 5   | V <sub>IO</sub> | Digital Input / Output pins supply voltage. On NCV7357-3 only                                    |
| 6   | CANL            | Low-level CAN bus line (low in dominant mode)  |
| 7   | CANH            | High-level CAN bus line (high in dominant mode)  |
| 8   | S               | Silent mode control input; internal pull-up current  |
|     | EP              | Exposed Pad. Recommended to connect to GND or left floating in application (DFNW8 package only). |

#### **FUNCTIONAL DESCRIPTION**

#### High speed CAN FD transceiver

NCV7357 implements high–speed physical layer CAN FD transceiver compatible with ISO11898–2, implementing following optional features or alternatives:

• Extended bus load range

#### **Operating Modes**

NCV7357 provides two modes of operation as illustrated in Table 2. These modes are selectable through pin S.

**Table 2. OPERATING MODES** 

| Pin S | Mode     | Pin TxD | BUS             | Pin RxD |
|-------|----------|---------|-----------------|---------|
| Low   | Normal   | 0       | Dominant        | 0       |
| Low   | inormai  | 1       | Recessive       | 1       |
| High  | n Silent | Х       | Dominant<br>(1) | 0       |
|       |          | Х       | Recessive       | 1       |

1. CAN BUS driven by another transceiver on the BUS

2. 'X' = don't care

#### Power-off

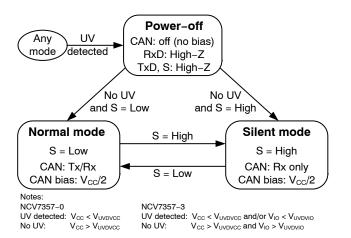
This virtual mode is entered as soon as the  $V_{CC}$  or  $V_{IO}$  undervoltage condition is detected. The internal logic is reset and the transceiver is disabled. CAN bus pins are kept floating. As soon as both  $V_{CC}$  and  $V_{IO}$  voltages rise above corresponding undervoltage recovery thresholds, the device proceeds to Normal or Silent mode, depending on S pin state.

#### **Normal Mode**

In the normal mode, the transceiver is able to communicate via the bus lines. The signals are transmitted and received to the CAN controller via the pins TxD and RxD. The slopes on the bus lines outputs are optimized to give low EME.

#### Silent Mode

In the silent mode, the transmitter is disabled. The bus pins are in recessive state independent of TxD input. Transceiver listens to the bus and provides data to controller, but controller is prevented from sending any data to the bus.



- Transmit dominant timeout, long
- Support of bit rates up to 5 Mbps
- Normal Bus biasing

#### **Overtemperature Detection**

A thermal protection circuit protects the IC from damage by switching off the transmitter if the junction temperature exceeds T<sub>J(sd)</sub> value. Because the transmitter dissipates most of the power, the power dissipation and temperature of the IC is reduced. All other IC functions continue to operate. The transmitter off–state resets when the temperature decreases below the shutdown threshold and pin TxD goes high. The thermal protection circuit is particularly needed when a bus line short circuits.

#### **TxD Dominant Timeout Function**

A TxD dominant timeout timer circuit prevents the bus lines being driven to a permanent dominant state (blocking all network communication) if pin TxD is forced permanently low by a hardware and/or software application failure. The timer is triggered by a negative edge on pin TxD. If the duration of the low–level on pin TxD exceeds the internal timer value  $t_{\text{dom}(TxD)}$ , the transmitter is disabled, driving the bus into a recessive state. The timer is reset by a positive edge on pin TxD.

This TxD dominant timeout time  $t_{dom(TxD)}$  defines the minimum possible bit rate to 17 kbps.

#### **Fail Safe Features**

A current-limiting circuit protects the transmitter output stage from damage caused by accidental short circuit to either positive or negative supply voltage, although power dissipation increases during this fault condition.

Detection of undervoltage on supply pin ( $V_{CC}$  or  $V_{IO}$ ) causes switching off device. After supply voltage is recovered TxD pin must be first released to high to allow sending dominant bits again.

The pins CANH and CANL are protected from automotive electrical transients (according to ISO 7637; see

Figure 7). Pins TxD and S are biased internally should the input become disconnected. Pins TxD, S and RxD will be floating, preventing reverse supply should the VCC supply be removed.

#### **V<sub>IO</sub> Supply Pin**

The  $V_{\rm IO}$  pin (available only on NCV7357–3 version) should be connected to microcontroller supply pin. By using  $V_{\rm IO}$  supply pin shared with microcontroller the I/O levels between microcontroller and transceiver are properly adjusted. See Figure 4.

#### **ABSOLUTE MAXIMUM RATINGS**

**Table 3. ABSOLUTE MAXIMUM RATINGS** 

| Symbol                   | Parameter  | Conditions                                 | Min  | Max                       | Unit |
|--------------------------|--|--|------|---------------------------|------|
| V <sub>SUP</sub>         | Supply voltage V <sub>CC</sub> , V <sub>IO</sub>                                 |  | -0.3 | +6.0                      | V    |
| V <sub>CANH</sub>        | DC voltage at pin CANH   | 0 < V <sub>CC</sub> < 5.5 V; no time limit | -42  | +42                       | V    |
| $V_{CANL}$               | DC voltage at pin CANL   | 0 < V <sub>CC</sub> < 5.5 V; no time limit | -42  | +42                       | V    |
| V <sub>CANH - CANL</sub> | DC voltage between CANH and CANL   |  | -42  | +42                       | V    |
| V <sub>IN</sub>          | DC voltage at pin TxD, S   |  | -0.3 | +6.0                      | V    |
| V <sub>OUT</sub>         | DC voltage at pin RxD  |  | -0.3 | V <sub>SUP</sub><br>+ 0.3 | V    |
| V <sub>esdHBM</sub>      | Electrostatic discharge voltage at all pins, Component HBM                       | (Note 3)                                   | -6   | +6                        | kV   |
| V <sub>esdCDM</sub>      | Electrostatic discharge voltage at all pins, Component CDM                       | (Note 4)                                   | -750 | +750                      | V    |
| V <sub>esdIEC</sub>      | Electrostatic discharge voltage at pins<br>CANH and CANL,<br>System HBM (Note 6) | (Note 5)                                   | -8   | +8                        | kV   |
| V <sub>schaff</sub>      | Voltage transients, pins CANH, CANL.   | test pulses 1                              | -100 |                           | V    |
|                          | Test Pulses According to ISO7637–2,<br>Class C (Note 6)                          | test pulses 2a                             |      | +75                       | V    |
|                          |  | test pulses 3a                             | -150 |                           | V    |
|                          |  | test pulses 3b                             |      | +100                      | V    |
| Latch-up                 | Static latch-up at all pins  | (Note 7)                                   |      | 150                       | mA   |
| T <sub>stg</sub>         | Storage temperature  |  | -55  | +150                      | °C   |
| TJ                       | Maximum junction temperature   |  | -40  | +170                      | °C   |
| MSL <sub>SOIC</sub>      | Moisture sensitivity level for SOIC-8  |  | 2    | 2                         | -    |
| MSL <sub>DEN</sub>       | Moisture sensitivity level for DFNW8   | Moisture sensitivity level for DFNW8       |      |                           | _    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Standardized human body model electrostatic discharge (ESD) pulses in accordance to EIA–JESD22. Equivalent to discharging a 100 pF capacitor through a 1.5 kΩ resistor
- 4. Standardized charged device model ESD pulses when tested according to AEC-Q100-011
- 5. System human body model electrostatic discharge (ESD) pulses in accordance to IEC 61000-4-2. Equivalent to discharging a 150 pF capacitor through a 330 Ω resistor referenced to GND
- 6. Results were verified by external test house
- 7. Static latch-up immunity: Static latch-up protection level when tested according to EIA/JESD78

**Table 4. THERMAL CHARACTERISTICS** 

| Parameter  | Symbol                               | Value     | Unit         |
|--|--------------------------------------|-----------|--------------|
| Thermal characteristics SOIC-8 (Note 8) Thermal Resistance Junction-to-Air, Free air, 1S0P PCB (Note 9) Thermal Resistance Junction-to-Air, Free air, 2S2P PCB (Note 10) | $R_{	hetaJA} \ R_{	hetaJA}$          | 131<br>81 | °C/W<br>°C/W |
| Thermal characteristics DFNW8 (Note 8) Thermal Resistance Junction-to-Air, Free air, 1S0P PCB (Note 9) Thermal Resistance Junction-to-Air, Free air, 2S2P PCB (Note 10)  | R <sub>θJA</sub><br>R <sub>θJA</sub> | 125<br>58 | °C/W<br>°C/W |

<sup>8.</sup> Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for Safe Operating parameters

**Table 5. ELECTRICAL CHARACTERISTICS** ( $V_{CC}=4.75\ V$  to  $5.25\ V$ ;  $V_{IO}=2.8\ V$  to  $5.5\ V$ ; for typical values  $T_A=25^{\circ}C$ , for min/max values  $T_J=-40$  to  $+150^{\circ}C$ ;  $R_{LT}=60\ \Omega$ ,  $C_{RxD}=15\ pF$ ; unless otherwise noted. All voltages are referenced to GND (pin 2). Positive currents flow into the respective pin)

| Symbol                      | Parameter   | Conditions  | Min  | Тур  | Max  | Unit |
|-----------------------------|---|---|------|------|------|------|
| SUPPLY (Pin V <sub>C0</sub> | <del>.</del>  |   |      |      |      |      |
| V <sub>CC</sub>             | Power supply voltage                                    | (Note 11)   | 4.75 | 5.0  | 5.25 | V    |
| I <sub>CC</sub>             | Supply current in Normal mode                           | Dominant; V <sub>TxD</sub> = Low  | 30   | 45   | 55   | mA   |
|                             |   | Recessive; V <sub>TxD</sub> = High  | 2.0  | 5.0  | 10   | mA   |
|                             |   | Normal mode, Dominant; $V_{TxD} = 0 \text{ V}$ ; one of bus wires shorted $-3 \text{ V} \le (V_{CANH}, V_{CANL}) \le +18 \text{ V}$ | 2.0  | -    | 105  | mA   |
| I <sub>CCS</sub>            | Supply current in silent mode NCV7357–3 version         |   | 0.1  | _    | 1.3  | mA   |
|                             | Supply current in silent mode NCV7357-0 version         |   | 0.1  | _    | 1.5  | mA   |
| V <sub>UVDVCC</sub>         | Undervoltage detection on V <sub>CC</sub> pin           |   | 3.5  | 4.0  | 4.3  | V    |
| V <sub>IO</sub> SUPPLY VO   | LTAGE (Pin V <sub>IO</sub> ) Only for NCV7357-3 version |   |      |      |      |      |
| V <sub>IO</sub>             | Supply voltage on pin V <sub>IO</sub>                   |   | 2.8  | -    | 5.5  | V    |
| I <sub>IOS</sub>            | Supply current on pin V <sub>IO</sub> in silent mode    | V <sub>TxD</sub> = VIO  | -    | 120  | 200  | μА   |
|                             | Supply current on pin V <sub>IO</sub> during normal     | Dominant; V <sub>TxD</sub> = Low  | -    | 700  | 900  |      |
| IONM                        | mode  | Recessive; V <sub>TxD</sub> = High  | -    | 460  | 600  | μΑ   |
| V <sub>UVDVIO</sub>         | Undervoltage detection voltage on V <sub>IO</sub> pin   |   | 2.0  | 2.3  | 2.6  | V    |
| TRANSMITTER D               | DATA INPUT (Pin TxD)                                    |   | •    | •    | •    |      |
| V <sub>IH</sub>             | High-level input voltage                                | Output recessive  | 2.0  | -    | -    | V    |
| V <sub>IL</sub>             | Low-level input voltage                                 | Output dominant   | -0.3 | -    | 0.8  | V    |
| I <sub>IH</sub>             | High-level input current                                | $V_{TxD} = V_{CC} / V_{IO}$   | -5.0 | 0    | 5.0  | μА   |
| I <sub>IL</sub>             | Low-level input current                                 | V <sub>TxD</sub> = 0 V  | -300 | -150 | -75  | μА   |
| C <sub>i</sub>              | Input capacitance                                       | (Note 12)   | -    | 5    | 10   | pF   |
| TRANSMITTER D               | DATA INPUT (Pin S)                                      |   | •    | •    | •    |      |
| $V_{IH}$                    | High-level input voltage                                | Silent mode   | 2.0  | -    | _    | V    |
| $V_{IL}$                    | Low-level input voltage                                 | Normal mode   | -0.3 | -    | 0.8  | V    |
| I <sub>IH</sub>             | High-level input current                                | $V_S = V_{CC} / V_{IO}$   | -1.0 | 0    | 1.0  | μА   |
| I <sub>IL</sub>             | Low-level input current                                 | V <sub>S</sub> = 0 V  | -15  | -    | -1.0 | μА   |
| C <sub>i</sub>              | Input capacitance                                       | (Note 12)   | -    | 5    | 10   | pF   |

Values based on test board according to EIA/JEDEC Standard JESD51-3, signal layer with 10% trace coverage
 Values based on test board according to EIA/JEDEC Standard JESD51-7, signal layers with 10% trace coverage

**Table 5. ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = 4.75 V to 5.25 V;  $V_{IO}$  = 2.8 V to 5.5 V; for typical values  $T_A$  = 25°C, for min/max values  $T_J$  = -40 to +150°C;  $R_{LT}$  = 60  $\Omega$ ,  $C_{RXD}$  = 15 pF; unless otherwise noted. All voltages are referenced to GND (pin 2). Positive currents flow into the respective pin)

#### RECEIVER DATA OUTPUT (Pin RxD)

| I <sub>OH</sub>              | High-level output current   | Normal mode $V_{RxD} = V_{CC} / V_{IO} - 0.4 V$  | -8.0 | -3.0 | -1.0 | mA              |
|------------------------------|---|--|------|------|------|-----------------|
| I <sub>OL</sub>              | Low-level output current  | V <sub>RxD</sub> = 0.4 V   | 1.0  | 6.0  | 12   | mA              |
| AN TRANSMITTI                | ER (PINS CANH AND CANL)   |  |      |      |      |                 |
| V <sub>o(dom)</sub> (CANH)   | Dominant output voltage at pin CANH   | Normal mode; $V_{TxD}$ = Low;<br>t < t <sub>dom(TxD)</sub> ; 50 $\Omega$ < R <sub>LT</sub> < 65 $\Omega$   | 2.75 | 3.5  | 4.5  | ٧               |
| V <sub>o(dom)</sub> (CANL)   | Dominant output voltage at pin CANL   | Normal mode; $V_{TxD}$ = Low;<br>t < t <sub>dom(TxD)</sub> ; 50 $\Omega$ < R <sub>LT</sub> < 65 $\Omega$   | 0.5  | 1.5  | 2.25 | V               |
| $V_{o(rec)}$                 | Recessive output voltage at pins CANH and CANL  | $\begin{aligned} & \text{Normal or Silent mode;} \\ & V_{TXD} = \text{High} \\ & \text{or } V_{TXD} = \text{Low and t} > t_{\text{dom}(TxD);} \\ & \text{no load} \end{aligned}$ | 2.0  | 2.5  | 3.0  | ٧               |
| $V_{o(dom)(diff)}$           | Differential dominant output voltage<br>(V <sub>CANH</sub> - V <sub>CANL</sub> )                | Normal mode; $V_{TxD}$ = Low;<br>t < t <sub>dom(TxD)</sub> ; 45 $\Omega$ < R <sub>LT</sub> < 65 $\Omega$   | 1.5  | 2.25 | 3.0  | V               |
| $V_{o(dom)(diff)\_ARB}$      |   | Normal mode; $V_{TxD}$ = Low;<br>t < $t_{dom(TxD)}$ ; $R_{LT}$ = 2 240 $\Omega$<br>(Note 12)   | 1.5  | -    | 5.0  | ٧               |
| V <sub>o(rec)(diff)</sub>    | Differential recessive output voltage<br>(V <sub>CANH</sub> – V <sub>CANL</sub> )               | Normal or Silent mode; $V_{TXD} = \text{High}$ or $V_{TXD} = \text{Low and t} > t_{\text{dom}(TXD)};$ no load  | -50  | 0    | +50  | mV              |
| $V_{o(dom)(sym)}$            | Dominant output voltage driver symmetry $V_{O(dom)(sym)} = V_{O(CANH)(dom)} + V_{O(CANL)(dom)}$ | TxD = square wave up to 1 MHz;<br>C <sub>ST</sub> = 4.7 nF   | 0.9  | 1.0  | 1.1  | V <sub>CC</sub> |
| I <sub>o(sc)(CANH)</sub>     | Short circuit output current at pin CANH in dominant  | Normal mode; TxD = Low,<br>$t < t_{dom(TxD)}$ ; -3 $V \le V_{CANH} \le$<br>+18 $V$   | -100 | -70  | +1.0 | mA              |
| I <sub>o(sc)</sub> (CANL)    | Short circuit output current at pin CANL in dominant  | Normal mode; TxD = Low,<br>$t < t_{dom(TxD)}$ ; $-3 \ V \le V_{CANL} \le +36 \ V$  | -1.0 | +70  | +100 | mA              |
| I <sub>o(sc)(rec)</sub>      | Short circuit output current at pins CANH and CANL in recessive                                 | Normal or Silent mode;<br>TxD = High,<br>-27 V < V <sub>CANH</sub> , V <sub>CANL</sub> < +32 V   | -5.0 | -    | +5.0 | mA              |
| AN RECEIVER (I               | Pins CANH and CANL)   |  |      |      |      |                 |
| I <sub>LEAK(off)</sub>       | Input leakage current   | $0 \Omega$ < R(V <sub>CC</sub> to GND) < 1 MΩ<br>V <sub>CANH</sub> = V <sub>CANL</sub> = 5 V   | -5.0 | 0    | +5.0 | μΑ              |
|                              |   | $V_{CC} = V_{IO} = 0 \text{ V}$ $V_{CANH} = V_{CANL} = 5 \text{ V}$  | -5.0 | 0    | +5.0 | μΑ              |
| V <sub>i(rec)(diff)_NM</sub> | Differential input voltage range recessive state  | Normal or Silent mode;<br>-12 V ≤ V <sub>CANH</sub> , V <sub>CANL</sub> ≤ +12 V;<br>no load  | -3.0 | -    | 0.5  | ٧               |
| $v_{i(dom)(diff)\_NM}$       | Differential input voltage range dominant state   | Normal or Silent mode;<br>-12 V ≤ V <sub>CANH</sub> , V <sub>CANL</sub> ≤ +12 V;<br>no load  | 0.9  | -    | 8.0  | ٧               |
| $V_{i(th)(diff)\_NM}$        | Differential receiver threshold voltage voltage   | Normal or Silent mode;<br>-12 V ≤ V <sub>CANH</sub> , V <sub>CANL</sub> ≤ +12 V;<br>no load  | 0.5  | -    | 0.9  | ٧               |
| $V_{i(th)(diff)\_NM\_E}$     |   | Normal or Silent mode; extended,<br>-30 V ≤ V <sub>CANH</sub> , V <sub>CANL</sub> ≤ +35 V;<br>no load  | 0.4  | -    | 1.0  | ٧               |
| R <sub>i(cm)</sub>           | Common-mode input resistance at pins CANH and CANL  | -2 V ≤ V <sub>CANH</sub> , V <sub>CANL</sub> ≤ +7 V  | 15   | 25   | 37   | kΩ              |

**Table 5. ELECTRICAL CHARACTERISTICS** ( $V_{CC} = 4.75 \text{ V}$  to 5.25 V;  $V_{IO} = 2.8 \text{ V}$  to 5.5 V; for typical values  $T_A = 25^{\circ}\text{C}$ , for min/max values  $T_J = -40$  to  $+150^{\circ}\text{C}$ ;  $R_{LT} = 60 \Omega$ ,  $C_{RXD} = 15 \text{ pF}$ ; unless otherwise noted. All voltages are referenced to GND (pin 2). Positive currents flow into the respective pin)

| $R_{i(cm)(m)}$             | Matching between pin CANH and pin CANL common mode input resistance | V <sub>CANH</sub> = V <sub>CANL</sub> = + 5 V   | -1  | 0    | +1  | %  |
|----------------------------|---|---|-----|------|-----|----|
| R <sub>i(diff)</sub>       | Differential input resistance                                       | $\begin{aligned} R_{i(diff)} &= R_{i(cm)(CANH)} + \\ R_{i(cm)(CANL)} &-2 \text{ V} \leq \text{V}_{CANH}, \text{V}_{CANL} \leq +7 \text{ V} \end{aligned}$ | 25  | 50   | 75  | kΩ |
| C <sub>i</sub>             | Input capacitance at pins CANH and CANL                             | V <sub>TxD</sub> = High; (Note 12)  | -   | 7.5  | 20  | pF |
| C <sub>i(diff)</sub>       | Differential input capacitance                                      | V <sub>TxD</sub> = High; (Note 12)  | -   | 3.75 | 10  | pF |
| MING CHARAC                | TERISTICS (see Figure 5, Figure 6 and Figu                          | re 8)   |     |      |     |    |
| t <sub>d(TxD-BUSon)</sub>  | Propagation delay TxD to bus active                                 | Normal mode (Note 13)   | -   | 75   | _   | ns |
| t <sub>d(TxD-BUSoff)</sub> | Propagation delay TxD to bus inactive                               | Normal mode (Note 13)   | -   | 85   | _   | ns |
| t <sub>d(BUSon-RxD)</sub>  | Propagation delay bus active to RxD                                 | Normal or Silent mode (Note 13)   | -   | 24   | -   | ns |
| t <sub>d(BUSoff-RxD)</sub> | Propagation delay bus inactive to RxD                               | Normal or Silent mode (Note 13)   | -   | 32   | -   | ns |
| t <sub>pd_dr</sub>         | Propagation delay TxD to RxD dominant to recessive transition       | Normal mode (Note 13)   | 50  | 100  | 210 | ns |
| t <sub>pd_rd</sub>         | Propagation delay TxD to RxD recessive to dominant transition       | Normal mode (Note 13)   | 50  | 120  | 210 | ns |
| t <sub>d(s-nm)</sub>       | Operating mode change delay   | Silent mode to Normal mode  | 5.0 | 11   | 50  | μs |
| t <sub>dom(TxD)</sub>      | TxD dominant timeout  | Normal mode; V <sub>TxD</sub> = Low   | 1.0 | -    | 10  | ms |
| t <sub>bit(RxD)</sub>      | Bit time on RxD pin   | t <sub>bit(TxD)</sub> = 500 ns (Note 13)  | 400 | -    | 550 | ns |
|                            |   | t <sub>bit(TxD)</sub> = 200 ns (Note 13)  | 120 | _    | 220 | ns |

#### THERMAL SHUTDOWN

t<sub>bit(Vi(diff))</sub>

 $\Delta t_{\text{rec}}$ 

| $T_{J(sd)}$ | Shutdown junction temperature | Junction temperature rising | 160 | 180 | 200 | °C |
|-------------|-------------------------------|-----------------------------|-----|-----|-----|----|

 $t_{bit(TxD)} = 500 \text{ ns (Note 13)}$ 

 $t_{bit(T \times D)} = 200 \text{ ns (Note 13)}$ 

 $t_{bit(TxD)}$  = 500 ns (Note 13)

 $t_{bit(TxD)} = 200 \text{ ns (Note 13)}$ 

435

155

-65

-45

530

210

40

15

ns

ns

ns

ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Bit time on bus (CANH - CANL pin)

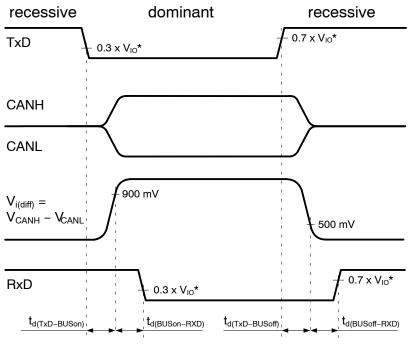
Receiver timing symmetry

 $\Delta t_{rec} = t_{bit(RxD)} - t_{bit(Vi(diff))}$ 

<sup>11.</sup> In the range between VUVDVCC and 4.75 V and from 5.25 V to 6 V the chip is fully functional; some parameters may be outside of the specification 12. Values based on design and characterization, not tested in production

<sup>13.</sup>  $C_{LT}$  = 100 pF,  $C_{ST}$  not present,  $C_{RxD}$  = 15 pF

#### **MEASUREMENTS SETUPS AND DEFINITIONS**



Edge length below 10 ns

Figure 5. Transceiver Timing Diagram - Propagation Delays

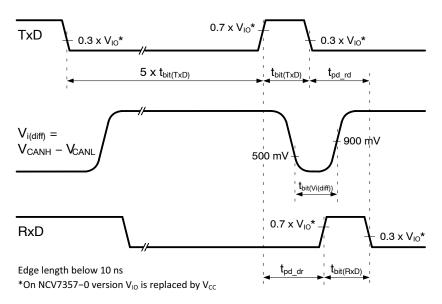
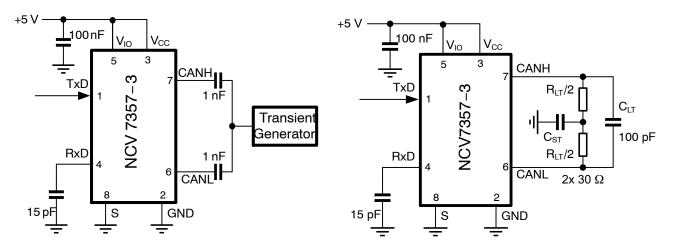


Figure 6. Transceiver Timing Diagram - Loop Delay and Recessive Bit Time

<sup>\*</sup>On NCV7357–0 version  $V_{\text{IO}}$  is replaced by  $V_{\text{CC}}$ 



**Figure 7. Test Circuit for Automotive Transients** 

Figure 8. Test Circuit for Timing Characteristics

Table 6. ISO 11898-2:2016 Parameter Cross-Reference Table

| ISO 11898-2:2016 Specification   |                       | NCV7357 Datasheet                        |
|--|-----------------------|--|
| Parameter  | Notation              | Symbol                                   |
| DOMINANT OUTPUT CHARACTERISTICS  |                       |  |
| Single ended voltage on CAN_H  | V <sub>CAN_H</sub>    | $V_{o(dom)(CANH)}$                       |
| Single ended voltage on CAN_L  | V <sub>CAN_L</sub>    | $V_{o(dom)(CANL)}$                       |
| Differential voltage on normal bus load                                  | $V_{Diff}$            | $V_{o(dom)(diff)}$                       |
| Differential voltage on effective resistance during arbitration          | $V_{Diff}$            | $V_{o(dom)(diff)\_ARB}$                  |
| Differential voltage on extended bus load range (optional)               | $V_{Diff}$            | $V_{o(dom)(diff)}$                       |
| DRIVER SYMMETRY  |                       |  |
| Driver symmetry  | V <sub>SYM</sub>      | V <sub>o(dom)(sym)</sub>                 |
| DRIVER OUTPUT CURRENT  |                       |  |
| Absolute current on CAN_H  | I <sub>CAN_H</sub>    | I <sub>o(SC)(CANH)</sub>                 |
| Absolute current on CAN_L  | I <sub>CAN_L</sub>    | I <sub>o(SC)(CANL)</sub>                 |
| RECEIVER OUTPUT CHARACTERISTICS, BUS BIASING ACTIVE                      |                       |  |
| Single ended output voltage on CAN_H                                     | V <sub>CAN_H</sub>    | V <sub>o(rec)</sub>                      |
| Single ended output voltage on CAN_L                                     | V <sub>CAN_L</sub>    | V <sub>o(rec)</sub>                      |
| Differential output voltage  | V <sub>Diff</sub>     | V <sub>o(rec)(diff)</sub>                |
| RECEIVER OUTPUT CHARACTERISTICS, BUS BIASING INACTIVE                    | 1                     |  |
| Single ended output voltage on CAN_H                                     | V <sub>CAN_H</sub>    | NA                                       |
| Single ended output voltage on CAN_L                                     | V <sub>CAN_L</sub>    | NA                                       |
| Differential output voltage  | V <sub>Diff</sub>     | NA                                       |
| OPTIONAL TRANSMIT DOMINANT TIMEOUT                                       | I I                   |  |
| Transmit dominant timeout, long  | t <sub>dom</sub>      | t <sub>dom(TxD)</sub>                    |
| Transmit dominant timeout, short   | t <sub>dom</sub>      | NA                                       |
| STATIC RECEIVER INPUT CHARACTERISTICS, BUS BIASING ACTIVE/ INACT         |                       |  |
| Recessive state differential input voltage range                         | $V_{Diff}$            | V <sub>i(rec)(diff)_NM</sub>             |
| Dominant state differential input voltage range                          | V <sub>Diff</sub>     | V <sub>i(dom)(diff)</sub> NM             |
| RECEIVER INPUT RESISTANCE  | Dill                  | i(doin)(diii)_ivivi                      |
| Differential internal resistance   | R <sub>Diff</sub>     | R <sub>i(diff)</sub>                     |
|  | R <sub>CAN_H</sub>    | R <sub>i(cm)</sub>                       |
| Single ended internal resistance   | R <sub>CAN_L</sub>    | R <sub>i(cm)</sub>                       |
| RECEIVER INPUT RESISTANCE MATCHING                                       |                       |  |
| Matching a of internal resistance  | m <sub>R</sub>        | R <sub>i(cm)(m)</sub>                    |
| IMPLEMENTATION LOOP DELAY REQUIREMENT                                    |                       |  |
| Loop delay   | t <sub>Loop</sub>     | t <sub>pd_rd</sub><br>t <sub>pd_dr</sub> |
| OPTIONAL IMPLEMENTATION DATA SIGNAL TIMING REQUIREMENTS FOR UTO 2 MBIT/S | JSE WITH BIT RATES    | · <del>-</del>                           |
| Transmitted recessive bit width @ 2 Mbit/s                               | t <sub>Bit(Bus)</sub> | t <sub>bit(Vi(diff))</sub>               |
| Received recessive bit width @ 2 Mbit/s                                  | t <sub>Bit(RXD)</sub> | t <sub>bit(RxD)</sub>                    |
| Receiver timing symmetry @ 2 Mbit/s                                      | $\Delta t_{Rec}$      | $\Delta t_rec$                           |
| OPTIONAL IMPLEMENTATION DATA SIGNAL TIMING REQUIREMENTS FOR UTO 5 MBIT/S |                       | S ABOVE 2 MBIT/S AND U                   |
| Transmitted recessive bit width @ 5 Mbit/s                               | t <sub>Bit(Bus)</sub> | t <sub>bit(Vi(diff))</sub>               |
|  |                       |  |

| Received recessive bit width @ 5 Mbit / s  | $\Delta t_{Rec}$                           | $\Delta t_{\sf rec}$                   |
|--|--|--|
| MAXIMUM RATINGS OF V <sub>CAN_H</sub> , V <sub>CAN_L</sub> AND V <sub>DIFF</sub> |  |  |
| Maximum rating V <sub>Diff</sub>   | V <sub>Diff</sub>                          | V <sub>CANH</sub> - CANL               |
| General maximum rating V <sub>CAN_H</sub> and V <sub>CAN_L</sub>                 | V <sub>CAN</sub> H<br>V <sub>CAN</sub> L   | V <sub>CANH</sub><br>V <sub>CANL</sub> |
| Optional: Extended maximum rating V <sub>CAN_H</sub> and V <sub>CAN_L</sub>      | V <sub>CAN_H</sub><br>V <sub>CAN_L</sub>   | NA                                     |
| MAXIMUM LEAKAGE CURRENTS ON CAN_H AND CAN_L, UNPOWERED                           | ·  |  |
| Leakage current on CAN_H, CAN_L  | I <sub>CAN_H</sub> ,<br>I <sub>CAN_L</sub> | I <sub>LEAK(off)</sub>                 |
| BUS BIASING CONTROL TIMINGS  |  |  |
| CAN activity filter time, long   | t <sub>Filter</sub>                        | NA                                     |
| CAN activity filter time, short  | t <sub>Filter</sub>                        | NA                                     |
| Wake-up timeout, short   | t <sub>Wake</sub>                          | NA                                     |
| Wake-up timeout, long  | t <sub>Wake</sub>                          | NA                                     |
| Timeout for bus inactivity (Required for selective wake-up implementation only)  | t <sub>Silence</sub>                       | NA                                     |
| Bus Bias reaction time (Required for selective wake-up implementation only)      | t <sub>Bias</sub>                          | NA                                     |

#### **Table 7. ORDERING INFORMATION**

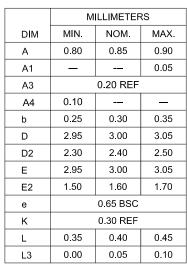
| Part Number   | Description   | Temperature Range | Package                              | Shipping           |
|---------------|---|-------------------|--------------------------------------|--------------------|
| NCV7357D10R2G | High Speed CAN FD<br>Transceiver                          | 40°C to .150°C    | SOIC 150 8 GREEN<br>(Matte Sn, JEDEC | 3000 / Tape & Reel |
| NCV7357D13R2G | High Speed CAN FD<br>Transceiver with V <sub>IO</sub> pin | -40°C to +150°C   | MS-012) (Pb-Free)                    | 3000 / Tape & Reel |
| NCV7357MW0R2G | High Speed CAN FD<br>Transceiver                          | –40°C to +150°C   | DFNW8<br>Wettable Flank              | 3000 / Tape & Reel |
| NCV7357MW3R2G | High Speed CAN FD<br>Transceiver with V <sub>IO</sub> pin | -40 C to +150 C   | (Pb-Free)                            | 3000 / Tape & Reel |

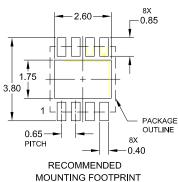
## DFNW8 3x3, 0.65P CASE 507AB ISSUE E SCALE 2:1

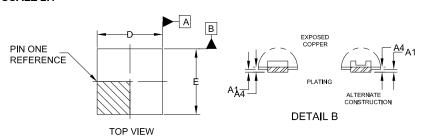
DATE 02 JUL 2021

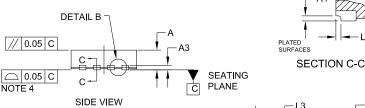
#### NOTES:

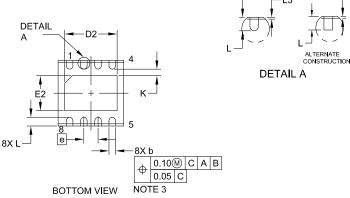
- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION & APPLIES TO PLATED
   TERMINALS AND IS MEASURED BETWEEN
   0.15 AND 0.30MM FROM THE TERMINAL TIP.
- 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
- 5. THIS DEVICE CONTAINS WETTABLE FLANK
  DESIGN FEATURES TO AID IN FILLET
  FORMATION ON THE LEADS DURING MOUNTING.











### GENERIC MARKING DIAGRAM\*



XXXXXX = Specific Device Code

A = Assembly Location

L = Wafer Lot

Y = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " =", may or may not be present. Some products may not follow the Generic Marking.

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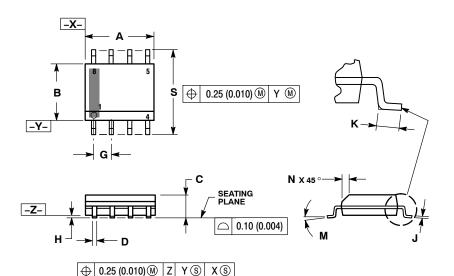
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SOIC-8 NB CASE 751-07 **ISSUE AK** 

**DATE 16 FEB 2011** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

|     | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
| DIM | MIN         | MAX  | MIN       | MAX   |
| Α   | 4.80        | 5.00 | 0.189     | 0.197 |
| В   | 3.80        | 4.00 | 0.150     | 0.157 |
| C   | 1.35        | 1.75 | 0.053     | 0.069 |
| D   | 0.33        | 0.51 | 0.013     | 0.020 |
| G   | 1.27 BSC    |      | 0.050 BSC |       |
| Н   | 0.10        | 0.25 | 0.004     | 0.010 |
| J   | 0.19        | 0.25 | 0.007     | 0.010 |
| K   | 0.40        | 1.27 | 0.016     | 0.050 |
| M   | 0 °         | 8 °  | 0 °       | 8 °   |
| N   | 0.25        | 0.50 | 0.010     | 0.020 |
| S   | 5.80        | 6.20 | 0.228     | 0.244 |

XXXXXX

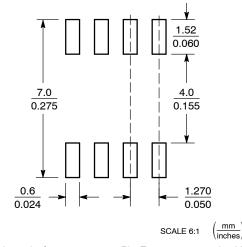
AYWW

Discrete

Ŧ  $\mathbb{H}$  AYWW

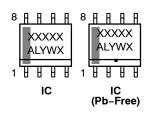
**Discrete** (Pb-Free)

#### **SOLDERING FOOTPRINT\***



<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **GENERIC MARKING DIAGRAM\***



XXXXX = Specific Device Code = Assembly Location = Wafer Lot = Year W

XXXXXX = Specific Device Code = Assembly Location Α = Year ww = Work Week = Work Week = Pb-Free Package = Pb-Free Package

> \*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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#### **DATE 16 FEB 2011**

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| PIN 1. DRAIN 2. DRAIN 3. DRAIN 4. DRAIN 5. GATE 6. GATE 7. SOURCE 8. SOURCE  | PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE   | STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd                            | PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 8. COLLECTOR, #1  |
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| STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3. CATHODE 3 4. CATHODE 4 5. CATHODE 5 6. COMMON ANODE 7. COMMON ANODE 8. CATHODE 6  | STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3. COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND | STYLE 23: PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT         | STYLE 24: PIN 1. BASE 2. EMITTER 3. COLLECTOR/ANODE 4. COLLECTOR/ANODE 5. CATHODE 6. CATHODE 7. COLLECTOR/ANODE 8. COLLECTOR/ANODE                                       |
| STYLE 25: PIN 1. VIN 2. N/C 3. REXT 4. GND 5. IOUT 6. IOUT 7. IOUT 8. IOUT   | STYLE 26: PIN 1. GND 2. dv/dt 3. ENABLE 4. ILIMIT 5. SOURCE 6. SOURCE 7. SOURCE 8. VCC  | STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN  | STYLE 28: PIN 1. SW_TO_GND 2. DASIC_OFF 3. DASIC_SW_DET 4. GND 5. V_MON 6. VBULK 7. VBULK 8. VIN   |
| STYLE 29: PIN 1. BASE, DIE #1 2. EMITTER, #1 3. BASE, #2 4. EMITTER, #2 5. COLLECTOR, #2 6. COLLECTOR, #2 7. COLLECTOR, #1 8. COLLECTOR, #1                        | STYLE 30: PIN 1. DRAIN 1 2. DRAIN 1 3. GATE 2 4. SOURCE 2 5. SOURCE 1/DRAIN 2 6. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 8. GATE 1                           |   |  |

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